

CMOS Inverter DC Characteristics

Outline

- ☐ CMOS Inverter DC Response
- ☐ Logic Levels and Noise Margins
- ☐ Transient Response
- ☐ Pass Transistors

DC Response

□ DC Response: V_{out} vs. V_{in} for a gate

□ Ex: Inverter

– When $V_{in} = 0$ $\rightarrow V_{out} = V_{DD}$

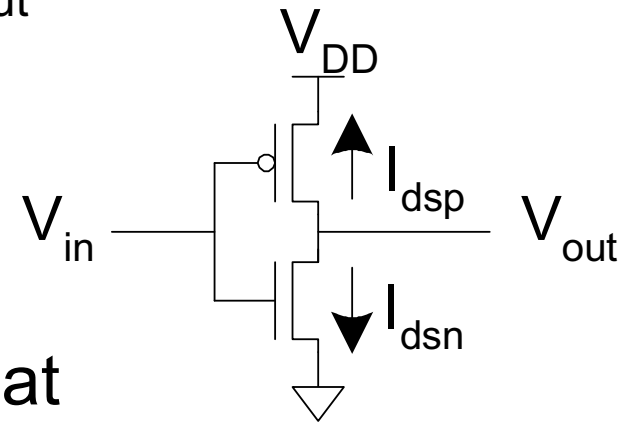
– When $V_{in} = V_{DD}$ $\rightarrow V_{out} = 0$

– In between, V_{out} depends on transistor size and current

– Assuming no load current:

• By KCL, must settle such that

$$I_{dsn} = |I_{dsp}|$$

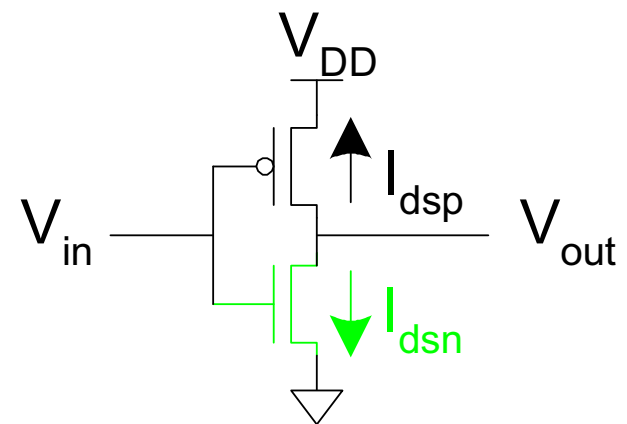


Transistor Operation

- ❑ Current depends on region of transistor behavior
- ❑ For what V_{in} and V_{out} are nMOS and pMOS in
 - Cutoff?
 - Linear?
 - Saturation?

nMOS Operation

Cutoff	Linear	Saturated
$V_{gsn} <$	$V_{gsn} >$ $V_{dsn} <$	$V_{gsn} >$ $V_{dsn} >$



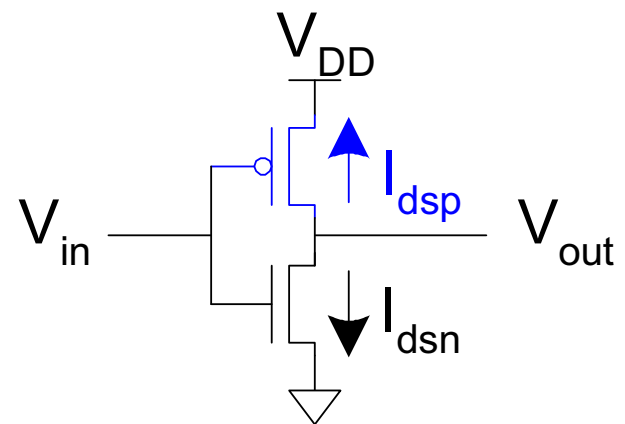
pMOS Operation

Cutoff	Linear	Saturated
$V_{gsp} > V_{tp}$ $V_{in} > V_{DD} + V_{tp}$	$V_{gsp} < V_{tp}$ $V_{in} < V_{DD} + V_{tp}$ $V_{dsp} > V_{gsp} - V_{tp}$ $V_{out} > V_{in} - V_{tp}$	$V_{gsp} < V_{tp}$ $V_{in} < V_{DD} + V_{tp}$ $V_{dsp} < V_{gsp} - V_{tp}$ $V_{out} < V_{in} - V_{tp}$

$$V_{gsp} = V_{in} - V_{DD}$$

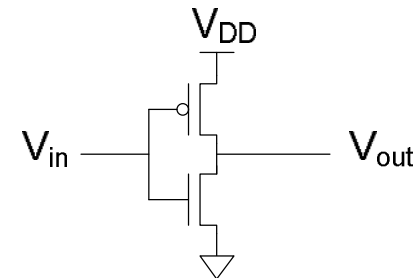
$$V_{tp} < 0$$

$$V_{dsp} = V_{out} - V_{DD}$$

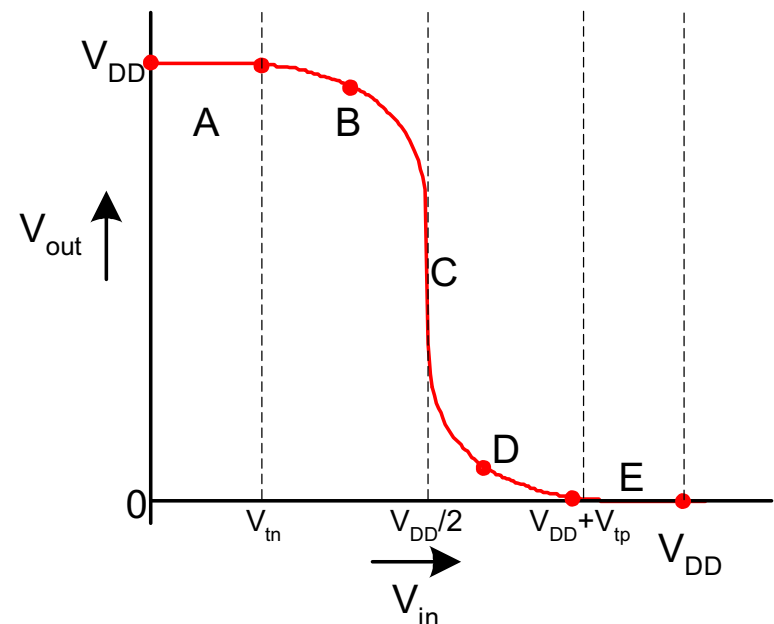


Voltage Transfer Characteristics

- ❑ Five operating regions for two transistors

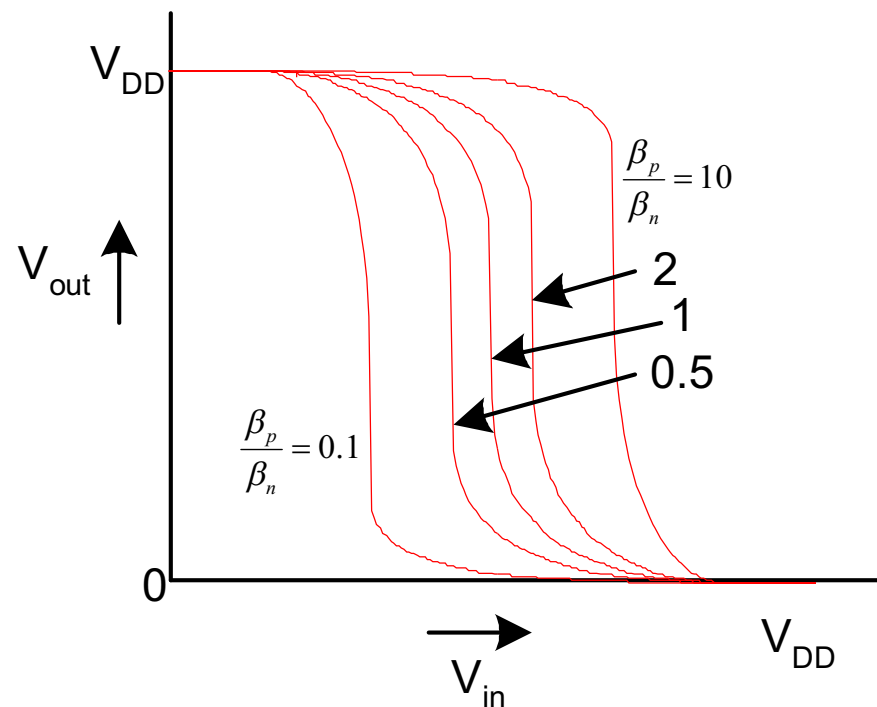


Region	nMOS	pMOS
A		
B		
C		
D		
E		



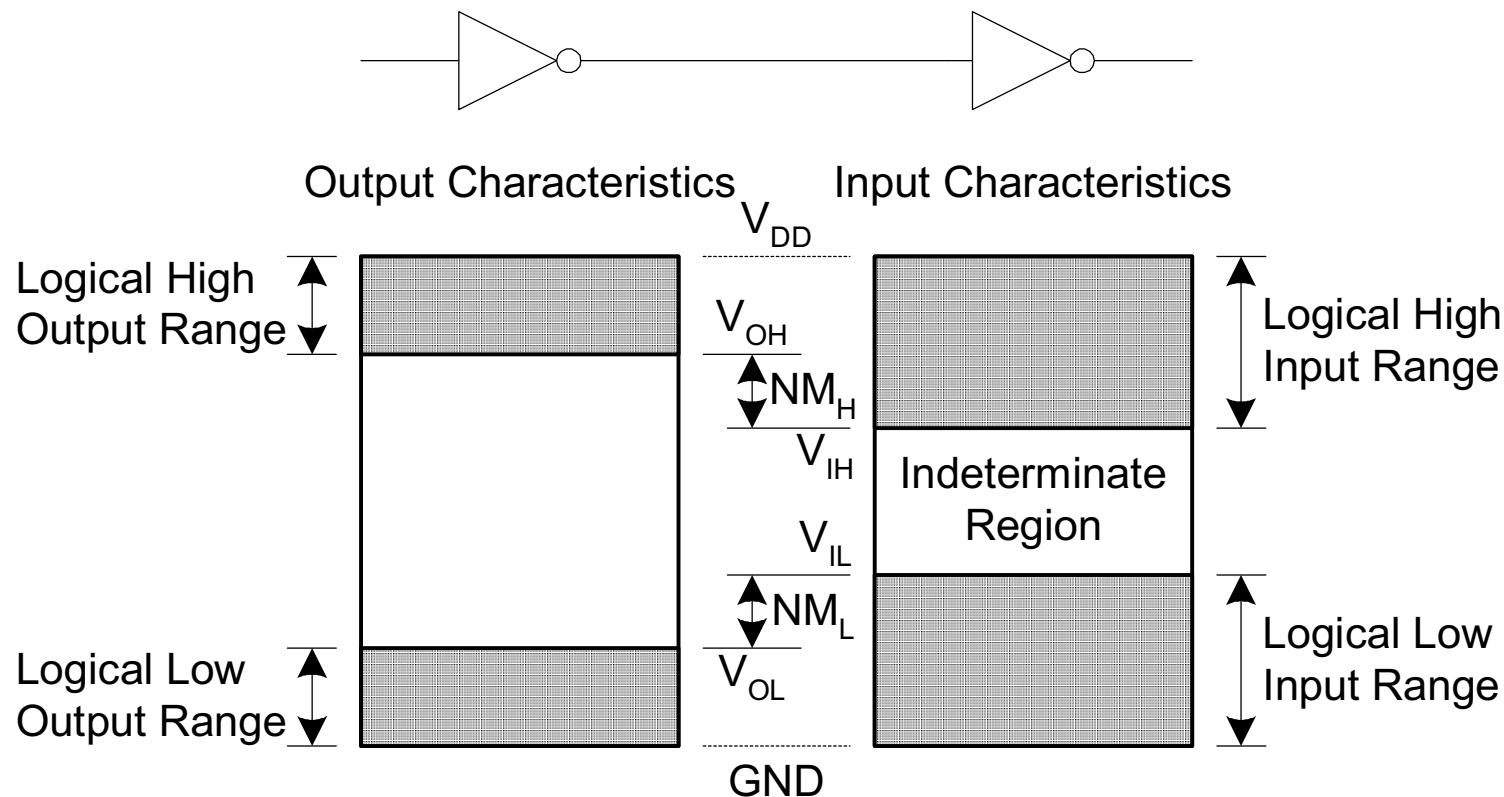
Beta Ratio

- ❑ If $\beta_p / \beta_n \neq 1$, switching point will move from $V_{DD}/2$
- ❑ Called *skewed gate*
- ❑ Other gates: collapse into equivalent inverter



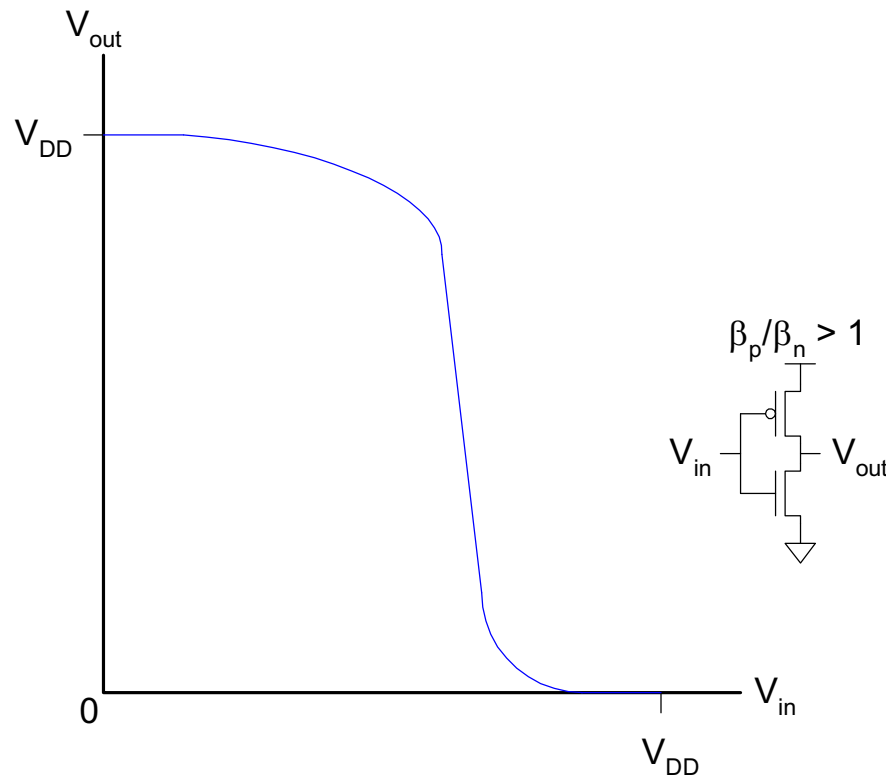
Noise Margins

- How much noise can a gate input see before it does not recognize the input?



Logic Levels

- ❑ Define critical voltages at:
 - unity gain point of DC transfer characteristic

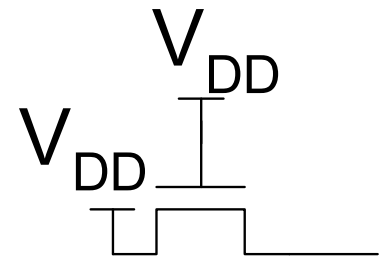


Transient Response

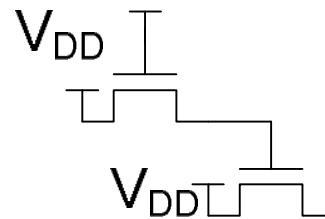
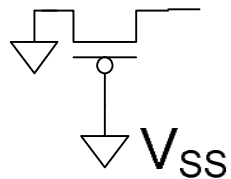
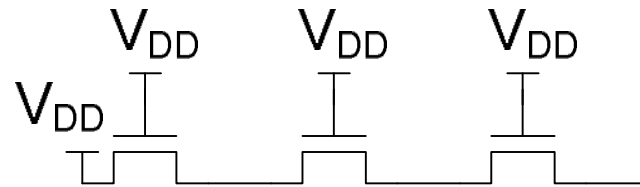
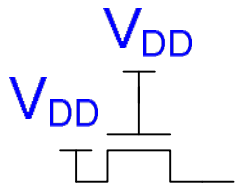
- ❑ *DC analysis* tells us V_{out} if V_{in} is constant
- ❑ *Transient analysis* tells us $V_{out}(t)$ if $V_{in}(t)$ changes
 - Requires solving differential equations
- ❑ Input is usually considered to be a step or ramp
 - From 0 to V_{DD} or vice versa

Pass Transistors

- ❑ We have assumed source is grounded
- ❑ What if source > 0 ?
 - e.g. pass transistor passing V_{DD}
- ❑ $V_g = V_{DD}$
 - If $V_s > V_{DD} - V_t$, $V_{gs} < V_t$
 - Hence transistor would turn itself off
- ❑ nMOS pass transistors pull no higher than $V_{DD} - V_{tn}$
 - Called a degraded “1”
 - Approach degraded value slowly (low I_{ds})
- ❑ pMOS pass transistors pull no lower than V_{tp}
- ❑ Transmission gates are needed to pass both 0 and 1



Pass Transistor Ckts



Homeworks

- ❑ Chapter 2 exercises: 2.16, 2.17, 2.20
- ❑ Due date: 1402/8/30